

## Development of scalable Silicon quantum computer technology

### Project manager

(selected in 2022)

**TARUCHA**  
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Science and Quantum computing



### Leader's institution

RIKEN

### R&D institutions

RIKEN

The University of Osaka

The University of Tokyo

Kobe University

AIST

### Summary of the project

This project aims to develop scalable multi-qubit devices toward realization of Silicon quantum computer. We will use sparse integration and medium-distance quantum coupling to implement a unit structure of qubits and scale up the qubit system by integrating the unit structures. Based on this method we will develop technology bases appropriate to implement large-scale quantum computers by 2030, and expand them in cooperation with the semiconductor industry to realize universal quantum computers by 2050.

### Milestone by 2030

We establish technology bases for fabricating multi-qubit devices toward development of large-scale quantum computers in cooperation with semiconductor industries. In parallel, we perform characterization and high-fidelity quantum operation of the multi-qubit devices, development of quantum channels suitable for connecting distant qubits, and production of isotopically enriched silicon/silicon-germanium (Si/SiGe) substrate, and in addition, demonstration of the principle of quantum error correction.



Figure 1 Qubit transfer channel.

### Milestone by 2025

We use high-quality substrate of Si/SiGe to establish fabrication technologies for implementing multi-qubit devices with a one-dimensional qubit array as a fundamental structure, and use them to construct a prototype of small- to middle-scale quantum computers. In addition, we inspect new principles for quantum gate circuits constructed by electron wave packets as propagating qubits.

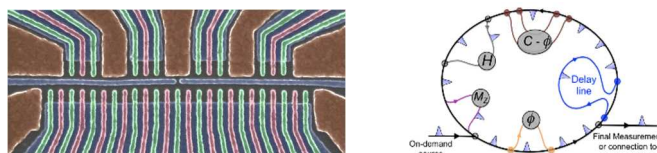


Figure 2 One-dimensional qubit array (left); Quantum gate circuit with electron wave packets as qubits (right).

### Project structure

Seigo Tarucha, Project Manager (RIKEN)

#### Development of scalable fault-tolerant Si quantum bit devices

Takashi Nakajima, RIKEN  
Takuji Miki, Kobe University

#### Development of middle-distance quantum link

Takafumi Fujita, The University of Osaka

#### Development of isotopically controlled Si/SiGe substrate technology

Satoru Miyamoto, AIST

#### Development of electron wave-packet qubits with new principle

Michihisa Yamamoto, RIKEN, The University of Tokyo  
Shintaro Takada, The University of Osaka

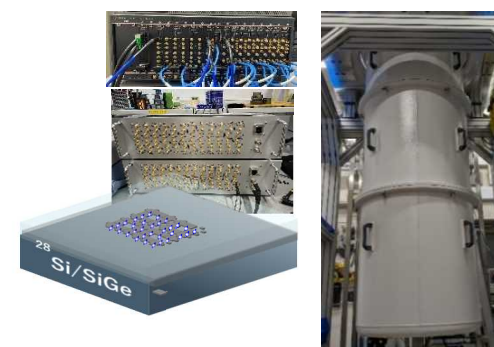


Figure 3 Silicon qubit device and the device operation setup: control electronics (left) and a dilution refrigerator (right).